

# 74HC245; 74HCT245

Octal bus transceiver; 3-state

Product data sheet

## 1. General description

The 74HC245; 74HCT245 is a high-speed Si-gate CMOS device and is pin compatible with Low-Power Schottky TTL (LSTTL).

The 74HC245; 74HCT245 is an octal transceiver featuring non-inverting 3-state bus compatible outputs in both send and receive directions. The 74HC245; 74HCT245 features an output enable input ( $\overline{OE}$ ) for easy cascading and a send/receive input (DIR) for direction control.  $\overline{OE}$  controls the outputs so that the buses are effectively isolated.

The 74HC245; 74HCT245 is similar to the 74HC640; 74HCT640 but has true (non-inverting) outputs.

## 2. Features

- Octal bidirectional bus interface
- Non-inverting 3-state outputs
- Multiple package options
- Complies with JEDEC standard no. 7A
- ESD protection:
  - ◆ HBM EIA/JESD22-A114-B exceeds 2000 V
  - ◆ MM EIA/JESD22-A115-A exceeds 200 V
- Specified from  $-40\text{ }^{\circ}\text{C}$  to  $+85\text{ }^{\circ}\text{C}$  and from  $-40\text{ }^{\circ}\text{C}$  to  $+125\text{ }^{\circ}\text{C}$

## 3. Quick reference data

**Table 1: Quick reference data**  
 $GND = 0\text{ V}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$ ;  $t_r = t_f = 6\text{ ns}$ .

| Symbol                | Parameter   | Conditions                                      | Min                 | Typ | Max | Unit |
|-----------------------|---|---|---------------------|-----|-----|------|
| <b>Type 74HC245</b>   |   |   |                     |     |     |      |
| $t_{PHL}$ , $t_{PLH}$ | propagation delay<br>An to Bn or Bn to An           | $C_L = 15\text{ pF}$ ;<br>$V_{CC} = 5\text{ V}$ | -                   | 7   | -   | ns   |
| $C_I$                 | input capacitance                                   |   | -                   | 3.5 | -   | pF   |
| $C_{I/O}$             | input/output capacitance                            |   | -                   | 10  | -   | pF   |
| $C_{PD}$              | power dissipation<br>capacitance per<br>transceiver | $V_I = GND\text{ to }V_{CC}$                    | <a href="#">1</a> - | 30  | -   | pF   |
| <b>Type 74HCT245</b>  |   |   |                     |     |     |      |
| $t_{PHL}$ , $t_{PLH}$ | propagation delay<br>An to Bn or Bn to An           | $C_L = 15\text{ pF}$ ;<br>$V_{CC} = 5\text{ V}$ | -                   | 10  | -   | ns   |

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**Table 1: Quick reference data ...continued** $GND = 0\text{ V}$ ;  $T_{amb} = 25\text{ °C}$ ;  $t_r = t_f = 6\text{ ns}$ .

| Symbol    | Parameter                                     | Conditions                             | Min | Typ | Max | Unit |
|-----------|---|--|-----|-----|-----|------|
| $C_I$     | input capacitance                             |  | -   | 3.5 | -   | pF   |
| $C_{I/O}$ | input/output capacitance                      |  | -   | 10  | -   | pF   |
| $C_{PD}$  | power dissipation capacitance per transceiver | $V_I = GND$ to $V_{CC} - 1.5\text{ V}$ | [1] | -   | 30  | pF   |

[1]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

$C_L$  = output load capacitance in pF;

$V_{CC}$  = supply voltage in V;

$N$  = number of inputs switching;

$\sum (C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

## 4. Ordering information

**Table 2: Ordering information**

| Type number | Package           |          |   |          |
|-------------|-------------------|----------|---|----------|
|             | Temperature range | Name     | Description   | Version  |
| 74HC245N    | -40 °C to +125 °C | DIP20    | plastic dual in-line package; 20 leads (300 mil)  | SOT146-1 |
| 74HC245D    | -40 °C to +125 °C | SO20     | plastic small outline package; 20 leads;<br>body width 7.5 mm   | SOT163-1 |
| 74HC245PW   | -40 °C to +125 °C | TSSOP20  | plastic thin shrink small outline package; 20 leads;<br>body width 4.4 mm   | SOT360-1 |
| 74HC245DB   | -40 °C to +125 °C | SSOP20   | plastic shrink small outline package; 20 leads;<br>body width 5.3 mm  | SOT339-1 |
| 74HC245BQ   | -40 °C to +125 °C | DHVQFN20 | plastic dual-in-line compatible thermal enhanced<br>very thin quad flat package no leads; 20 terminals;<br>body 2.5 × 4.5 × 0.85 mm | SOT764-1 |
| 74HCT245N   | -40 °C to +125 °C | DIP20    | plastic dual in-line package; 20 leads (300 mil)  | SOT146-1 |
| 74HCT245D   | -40 °C to +125 °C | SO20     | plastic small outline package; 20 leads;<br>body width 7.5 mm   | SOT163-1 |
| 74HCT245PW  | -40 °C to +125 °C | TSSOP20  | plastic thin shrink small outline package; 20 leads;<br>body width 4.4 mm   | SOT360-1 |
| 74HCT245DB  | -40 °C to +125 °C | SSOP20   | plastic shrink small outline package; 20 leads;<br>body width 5.3 mm  | SOT339-1 |
| 74HCT245BQ  | -40 °C to +125 °C | DHVQFN20 | plastic dual-in-line compatible thermal enhanced<br>very thin quad flat package no leads; 20 terminals;<br>body 2.5 × 4.5 × 0.85 mm | SOT764-1 |

Table 3: Pin description ...continued

| Symbol          | Pin | Description                      |
|-----------------|-----|----------------------------------|
| B1              | 17  | data input/output                |
| B0              | 18  | data input/output                |
| $\overline{OE}$ | 19  | output enable input (active LOW) |
| $V_{CC}$        | 20  | supply voltage                   |

## 7. Functional description

### 7.1 Function table

Table 4: Function table [1]

| Input           |     | Input/output |       |
|-----------------|-----|--------------|-------|
| $\overline{OE}$ | DIR | An           | Bn    |
| L               | L   | A = B        | input |
| L               | H   | input        | B = A |
| H               | X   | Z            | Z     |

- [1] H = HIGH voltage level;  
 L = LOW voltage level;  
 X = don't care;  
 Z = high-impedance OFF-state.

## 8. Limiting values

Table 5: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol            | Parameter                                   | Conditions   | Min  | Max      | Unit |
|-------------------|---|--|------|----------|------|
| $V_{CC}$          | supply voltage                              |  | -0.5 | +7       | V    |
| $I_{IK}$          | input diode current                         | $V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$ | -    | $\pm 20$ | mA   |
| $I_{OK}$          | output diode current                        | $V_O < -0.5\text{ V}$ or $V_O > V_{CC} + 0.5\text{ V}$ | -    | $\pm 20$ | mA   |
| $I_O$             | output source or sink current               | $V_O = -0.5\text{ V}$ to $V_{CC} + 0.5\text{ V}$       | -    | $\pm 35$ | mA   |
| $I_{CC}, I_{GND}$ | $V_{CC}$ or GND current                     |  | -    | $\pm 70$ | mA   |
| $T_{stg}$         | storage temperature                         |  | -65  | +150     | °C   |
| $P_{tot}$         | total power dissipation                     |  | [1]  |          |      |
|                   | DIP20 package                               |  | -    | 750      | mW   |
|                   | SO20, SSOP20, TSSOP20 and DHVQFN20 packages |  | -    | 500      | mW   |

- [1] For DIP20 packages: above 70 °C,  $P_{tot}$  derates linearly with 12 mW/K.  
 For SO20 packages: above 70 °C,  $P_{tot}$  derates linearly with 8 mW/K.  
 For SSOP20 and TSSOP20 packages: above 60 °C,  $P_{tot}$  derates linearly with 5.5 mW/K.  
 For DHVQFN20 packages: above 60 °C,  $P_{tot}$  derates linearly with 4.5 mW/K.

## 9. Recommended operating conditions

**Table 6: Recommended operating conditions**

| Symbol               | Parameter                 | Conditions              | Min | Typ | Max      | Unit |
|----------------------|---------------------------|-------------------------|-----|-----|----------|------|
| <b>Type 74HC245</b>  |                           |                         |     |     |          |      |
| $V_{CC}$             | supply voltage            |                         | 2.0 | 5.0 | 6.0      | V    |
| $V_I$                | input voltage             |                         | 0   | -   | $V_{CC}$ | V    |
| $V_O$                | output voltage            |                         | 0   | -   | $V_{CC}$ | V    |
| $t_r, t_f$           | input rise and fall times | $V_{CC} = 2.0\text{ V}$ | -   | -   | 1000     | ns   |
|                      |                           | $V_{CC} = 4.5\text{ V}$ | -   | 6.0 | 500      | ns   |
|                      |                           | $V_{CC} = 6.0\text{ V}$ | -   | -   | 400      | ns   |
| $T_{amb}$            | ambient temperature       |                         | -40 | -   | +125     | °C   |
| <b>Type 74HCT245</b> |                           |                         |     |     |          |      |
| $V_{CC}$             | supply voltage            |                         | 4.5 | 5.0 | 5.5      | V    |
| $V_I$                | input voltage             |                         | 0   | -   | $V_{CC}$ | V    |
| $V_O$                | output voltage            |                         | 0   | -   | $V_{CC}$ | V    |
| $t_r, t_f$           | input rise and fall times | $V_{CC} = 4.5\text{ V}$ | -   | 6.0 | 500      | ns   |
| $T_{amb}$            | ambient temperature       |                         | -40 | -   | +125     | °C   |

## 10. Static characteristics

**Table 7: Static characteristics type 74HC245**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                                     | Parameter                 | Conditions  | Min  | Typ  | Max  | Unit |
|--|---------------------------|---|------|------|------|------|
| <b><math>T_{amb} = 25\text{ °C}</math></b> |                           |   |      |      |      |      |
| $V_{IH}$                                   | HIGH-level input voltage  | $V_{CC} = 2.0\text{ V}$                               | 1.5  | 1.2  | -    | V    |
|  |                           | $V_{CC} = 4.5\text{ V}$                               | 3.15 | 2.4  | -    | V    |
|  |                           | $V_{CC} = 6.0\text{ V}$                               | 4.2  | 3.2  | -    | V    |
| $V_{IL}$                                   | LOW-level input voltage   | $V_{CC} = 2.0\text{ V}$                               | -    | 0.8  | 0.5  | V    |
|  |                           | $V_{CC} = 4.5\text{ V}$                               | -    | 2.1  | 1.35 | V    |
|  |                           | $V_{CC} = 6.0\text{ V}$                               | -    | 2.8  | 1.8  | V    |
| $V_{OH}$                                   | HIGH-level output voltage | $V_I = V_{IH}$ or $V_{IL}$                            |      |      |      |      |
|  |                           | $I_O = -20\text{ }\mu\text{A}; V_{CC} = 2.0\text{ V}$ | 1.9  | 2.0  | -    | V    |
|  |                           | $I_O = -20\text{ }\mu\text{A}; V_{CC} = 4.5\text{ V}$ | 4.4  | 4.5  | -    | V    |
|  |                           | $I_O = -20\text{ }\mu\text{A}; V_{CC} = 6.0\text{ V}$ | 5.9  | 6.0  | -    | V    |
|  |                           | $I_O = -6.0\text{ mA}; V_{CC} = 4.5\text{ V}$         | 3.98 | 4.32 | -    | V    |
|  |                           | $I_O = -7.8\text{ mA}; V_{CC} = 6.0\text{ V}$         | 5.48 | 5.81 | -    | V    |

**Table 7: Static characteristics type 74HC245 ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                                     | Parameter                 | Conditions   | Min  | Typ  | Max  | Unit |
|--|---------------------------|--|------|------|------|------|
| V <sub>OL</sub>                            | LOW-level output voltage  | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>  |      |      |      |      |
|  |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V  | -    | 0    | 0.1  | V    |
|  |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V  | -    | 0    | 0.1  | V    |
|  |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V  | -    | 0    | 0.1  | V    |
|  |                           | I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V   | -    | 0.15 | 0.26 | V    |
|  |                           | I <sub>O</sub> = 7.8 mA; V <sub>CC</sub> = 6.0 V   | -    | 0.16 | 0.26 | V    |
| I <sub>LI</sub>                            | input leakage current     | V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V   | -    | -    | ±0.1 | μA   |
| I <sub>OZ</sub>                            | OFF-state output current  | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V | -    | -    | ±0.5 | μA   |
| I <sub>CC</sub>                            | quiescent supply current  | V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 6.0 V                                 | -    | -    | 8.0  | μA   |
| C <sub>I</sub>                             | input capacitance         |  | -    | 3.5  | -    | pF   |
| C <sub>I/O</sub>                           | input/output capacitance  |  | -    | 10   | -    | pF   |
| <b>T<sub>amb</sub> = -40 °C to +85 °C</b>  |                           |  |      |      |      |      |
| V <sub>IH</sub>                            | HIGH-level input voltage  | V <sub>CC</sub> = 2.0 V  | 1.5  | -    | -    | V    |
|  |                           | V <sub>CC</sub> = 4.5 V  | 3.15 | -    | -    | V    |
|  |                           | V <sub>CC</sub> = 6.0 V  | 4.2  | -    | -    | V    |
| V <sub>IL</sub>                            | LOW-level input voltage   | V <sub>CC</sub> = 2.0 V  | -    | -    | 0.5  | V    |
|  |                           | V <sub>CC</sub> = 4.5 V  | -    | -    | 1.35 | V    |
|  |                           | V <sub>CC</sub> = 6.0 V  | -    | -    | 1.8  | V    |
| V <sub>OH</sub>                            | HIGH-level output voltage | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>  |      |      |      |      |
|  |                           | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V   | 1.9  | -    | -    | V    |
|  |                           | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V   | 4.4  | -    | -    | V    |
|  |                           | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V   | 5.9  | -    | -    | V    |
|  |                           | I <sub>O</sub> = -6.0 mA; V <sub>CC</sub> = 4.5 V  | 3.84 | -    | -    | V    |
|  |                           | I <sub>O</sub> = -7.8 mA; V <sub>CC</sub> = 6.0 V  | 5.34 | -    | -    | V    |
| V <sub>OL</sub>                            | LOW-level output voltage  | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>  |      |      |      |      |
|  |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V  | -    | -    | 0.1  | V    |
|  |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V  | -    | -    | 0.1  | V    |
|  |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V  | -    | -    | 0.1  | V    |
|  |                           | I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V   | -    | -    | 0.33 | V    |
|  |                           | I <sub>O</sub> = 7.8 mA; V <sub>CC</sub> = 6.0 V   | -    | -    | 0.33 | V    |
| I <sub>LI</sub>                            | input leakage current     | V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V   | -    | -    | ±1.0 | μA   |
| I <sub>OZ</sub>                            | OFF-state output current  | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V | -    | -    | ±5.0 | μA   |
| I <sub>CC</sub>                            | quiescent supply current  | V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 6.0 V                                 | -    | -    | 80   | μA   |
| <b>T<sub>amb</sub> = -40 °C to +125 °C</b> |                           |  |      |      |      |      |
| V <sub>IH</sub>                            | HIGH-level input voltage  | V <sub>CC</sub> = 2.0 V  | 1.5  | -    | -    | V    |
|  |                           | V <sub>CC</sub> = 4.5 V  | 3.15 | -    | -    | V    |
|  |                           | V <sub>CC</sub> = 6.0 V  | 4.2  | -    | -    | V    |

**Table 7: Static characteristics type 74HC245 ...continued**  
 At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol          | Parameter                 | Conditions   | Min | Typ | Max   | Unit |
|-----------------|---------------------------|--|-----|-----|-------|------|
| V <sub>IL</sub> | LOW-level input voltage   | V <sub>CC</sub> = 2.0 V  | -   | -   | 0.5   | V    |
|                 |                           | V <sub>CC</sub> = 4.5 V  | -   | -   | 1.35  | V    |
|                 |                           | V <sub>CC</sub> = 6.0 V  | -   | -   | 1.8   | V    |
| V <sub>OH</sub> | HIGH-level output voltage | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>  | -   | -   | -     | -    |
|                 |                           | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V   | 1.9 | -   | -     | V    |
|                 |                           | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V   | 4.4 | -   | -     | V    |
|                 |                           | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V   | 5.9 | -   | -     | V    |
|                 |                           | I <sub>O</sub> = -6.0 mA; V <sub>CC</sub> = 4.5 V  | 3.7 | -   | -     | V    |
|                 |                           | I <sub>O</sub> = -7.8 mA; V <sub>CC</sub> = 6.0 V  | 5.2 | -   | -     | V    |
| V <sub>OL</sub> | LOW-level output voltage  | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>  | -   | -   | -     | -    |
|                 |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V  | -   | -   | 0.1   | V    |
|                 |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V  | -   | -   | 0.1   | V    |
|                 |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V  | -   | -   | 0.1   | V    |
|                 |                           | I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V   | -   | -   | 0.4   | V    |
|                 |                           | I <sub>O</sub> = 7.8 mA; V <sub>CC</sub> = 6.0 V   | -   | -   | 0.4   | V    |
| I <sub>LI</sub> | input leakage current     | V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V   | -   | -   | ±1.0  | μA   |
| I <sub>OZ</sub> | OFF-state output current  | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V | -   | -   | ±10.0 | μA   |
| I <sub>CC</sub> | quiescent supply current  | V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 6.0 V                                 | -   | -   | 160   | μA   |

**Table 8: Static characteristics type 74HCT245**  
 At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                         | Parameter                 | Conditions   | Min  | Typ  | Max  | Unit |
|--------------------------------|---------------------------|--|------|------|------|------|
| <b>T<sub>amb</sub> = 25 °C</b> |                           |  |      |      |      |      |
| V <sub>IH</sub>                | HIGH-level input voltage  | V <sub>CC</sub> = 4.5 V to 5.5 V   | 2.0  | 1.6  | -    | V    |
| V <sub>IL</sub>                | LOW-level input voltage   | V <sub>CC</sub> = 4.5 V to 5.5 V   | -    | 1.2  | 0.8  | V    |
| V <sub>OH</sub>                | HIGH-level output voltage | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 4.5 V  | -    | -    | -    | -    |
|                                |                           | I <sub>O</sub> = -20 μA  | 4.4  | 4.5  | -    | V    |
|                                |                           | I <sub>O</sub> = -6 mA   | 3.98 | 4.32 | -    | V    |
| V <sub>OL</sub>                | LOW-level output voltage  | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 4.5 V  | -    | -    | -    | -    |
|                                |                           | I <sub>O</sub> = 20 μA   | -    | 0    | 0.1  | V    |
|                                |                           | I <sub>O</sub> = 6.0 mA  | -    | 0.15 | 0.26 | V    |
| I <sub>LI</sub>                | input leakage current     | V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5 V   | -    | -    | ±0.1 | μA   |
| I <sub>OZ</sub>                | OFF-state output current  | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 5.5 V; V <sub>O</sub> = V <sub>CC</sub> or GND per input pin; other inputs at V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A | -    | -    | ±0.5 | μA   |
| I <sub>CC</sub>                | quiescent supply current  | V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V   | -    | -    | 8.0  | μA   |

**Table 8:** Static characteristics type 74HCT245 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol          | Parameter   | Conditions  | Min | Typ | Max | Unit    |
|-----------------|---|---|-----|-----|-----|---------|
| $I_{CC}$        | quiescent supply current                          | $V_I = V_{CC}$ or GND; $I_O = 0$ A;<br>$V_{CC} = 5.5$ V   | -   | -   | 160 | $\mu$ A |
| $\Delta I_{CC}$ | additional quiescent supply current per input pin | $V_I = V_{CC} - 2.1$ V; other inputs at<br>$V_I = V_{CC}$ or GND;<br>$V_{CC} = 4.5$ V to 5.5 V; $I_O = 0$ A |     |     |     |         |
|                 | An or Bn inputs                                   |   | -   | -   | 196 | $\mu$ A |
|                 | $\overline{OE}$ input                             |   | -   | -   | 735 | $\mu$ A |
|                 | DIR input   |   | -   | -   | 441 | $\mu$ A |

## 11. Dynamic characteristics

**Table 9:** Dynamic characteristics type 74HC245GND = 0 V; test circuit see [Figure 7](#).

| Symbol  | Parameter  | Conditions  | Min   | Typ               | Max             | Unit                 |
|---|--|---|-------|-------------------|-----------------|----------------------|
| <b><math>T_{amb} = 25</math> °C</b>                         |  |   |       |                   |                 |                      |
| $t_{PHL}$ , $t_{PLH}$                                       | propagation delay An to Bn or Bn to An                                     | see <a href="#">Figure 5</a><br>$V_{CC} = 2.0$ V<br>$V_{CC} = 4.5$ V<br>$V_{CC} = 5.0$ V; $C_L = 15$ pF<br>$V_{CC} = 6.0$ V | -     | 25<br>9<br>7<br>7 | 90<br>18<br>-   | ns<br>ns<br>ns<br>ns |
| $t_{PZH}$ , $t_{PZL}$                                       | 3-state output enable time $\overline{OE}$ to An or $\overline{OE}$ to Bn  | see <a href="#">Figure 6</a><br>$V_{CC} = 2.0$ V<br>$V_{CC} = 4.5$ V<br>$V_{CC} = 6.0$ V                                    | -     | 30<br>11<br>9     | 150<br>30<br>26 | ns<br>ns<br>ns       |
| $t_{PHZ}$ , $t_{PLZ}$                                       | 3-state output disable time $\overline{OE}$ to An or $\overline{OE}$ to Bn | see <a href="#">Figure 6</a><br>$V_{CC} = 2.0$ V<br>$V_{CC} = 4.5$ V<br>$V_{CC} = 6.0$ V                                    | -     | 41<br>15<br>12    | 150<br>30<br>26 | ns<br>ns<br>ns       |
| $t_{THL}$ , $t_{TLH}$                                       | output transition time   | see <a href="#">Figure 5</a><br>$V_{CC} = 2.0$ V<br>$V_{CC} = 4.5$ V<br>$V_{CC} = 6.0$ V                                    | -     | 14<br>5<br>4      | 60<br>12<br>10  | ns<br>ns<br>ns       |
| $C_{PD}$  | power dissipation capacitance per transceiver                              | $V_I =$ GND to $V_{CC}$   | [1] - | 30                | -               | pF                   |
| <b><math>T_{amb} = -40</math> °C to <math>+85</math> °C</b> |  |   |       |                   |                 |                      |
| $t_{PHL}$ , $t_{PLH}$                                       | propagation delay An to Bn or Bn to An                                     | see <a href="#">Figure 5</a><br>$V_{CC} = 2.0$ V<br>$V_{CC} = 4.5$ V<br>$V_{CC} = 6.0$ V                                    | -     | -<br>-<br>-       | 115<br>23<br>20 | ns<br>ns<br>ns       |

**Table 9: Dynamic characteristics type 74HC245 ...continued**  
*GND = 0 V; test circuit see Figure 7.*

| Symbol  | Parameter  | Conditions                   | Min | Typ | Max | Unit |
|---|--|------------------------------|-----|-----|-----|------|
| $t_{PZH}$ , $t_{PZL}$   | 3-state output enable time $\overline{OE}$ to An or $\overline{OE}$ to Bn  | see <a href="#">Figure 6</a> |     |     |     |      |
|   |  | $V_{CC} = 2.0\text{ V}$      | -   | -   | 190 | ns   |
|   |  | $V_{CC} = 4.5\text{ V}$      | -   | -   | 38  | ns   |
|   |  | $V_{CC} = 6.0\text{ V}$      | -   | -   | 33  | ns   |
| $t_{PHZ}$ , $t_{PLZ}$   | 3-state output disable time $\overline{OE}$ to An or $\overline{OE}$ to Bn | see <a href="#">Figure 6</a> |     |     |     |      |
|   |  | $V_{CC} = 2.0\text{ V}$      | -   | -   | 190 | ns   |
|   |  | $V_{CC} = 4.5\text{ V}$      | -   | -   | 38  | ns   |
|   |  | $V_{CC} = 6.0\text{ V}$      | -   | -   | 33  | ns   |
| $t_{THL}$ , $t_{TLH}$   | output transition time   | see <a href="#">Figure 5</a> |     |     |     |      |
|   |  | $V_{CC} = 2.0\text{ V}$      | -   | -   | 75  | ns   |
|   |  | $V_{CC} = 4.5\text{ V}$      | -   | -   | 15  | ns   |
|   |  | $V_{CC} = 6.0\text{ V}$      | -   | -   | 13  | ns   |
| <b><math>T_{amb} = -40\text{ }^{\circ}\text{C to }+125\text{ }^{\circ}\text{C}</math></b> |  |                              |     |     |     |      |
| $t_{PHL}$ , $t_{PLH}$   | propagation delay An to Bn or Bn to An                                     | see <a href="#">Figure 5</a> |     |     |     |      |
|   |  | $V_{CC} = 2.0\text{ V}$      | -   | -   | 135 | ns   |
|   |  | $V_{CC} = 4.5\text{ V}$      | -   | -   | 27  | ns   |
|   |  | $V_{CC} = 6.0\text{ V}$      | -   | -   | 23  | ns   |
| $t_{PZH}$ , $t_{PZL}$   | 3-state output enable time $\overline{OE}$ to An or $\overline{OE}$ to Bn  | see <a href="#">Figure 6</a> |     |     |     |      |
|   |  | $V_{CC} = 2.0\text{ V}$      | -   | -   | 225 | ns   |
|   |  | $V_{CC} = 4.5\text{ V}$      | -   | -   | 45  | ns   |
|   |  | $V_{CC} = 6.0\text{ V}$      | -   | -   | 38  | ns   |
| $t_{PHZ}$ , $t_{PLZ}$   | 3-state output disable time $\overline{OE}$ to An or $\overline{OE}$ to Bn | see <a href="#">Figure 6</a> |     |     |     |      |
|   |  | $V_{CC} = 2.0\text{ V}$      | -   | -   | 225 | ns   |
|   |  | $V_{CC} = 4.5\text{ V}$      | -   | -   | 45  | ns   |
|   |  | $V_{CC} = 6.0\text{ V}$      | -   | -   | 38  | ns   |
| $t_{THL}$ , $t_{TLH}$   | output transition time   | see <a href="#">Figure 5</a> |     |     |     |      |
|   |  | $V_{CC} = 2.0\text{ V}$      | -   | -   | 90  | ns   |
|   |  | $V_{CC} = 4.5\text{ V}$      | -   | -   | 18  | ns   |
|   |  | $V_{CC} = 6.0\text{ V}$      | -   | -   | 15  | ns   |

[1]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

$C_L$  = output load capacitance in pF;

$V_{CC}$  = supply voltage in V;

$N$  = number of inputs switching;

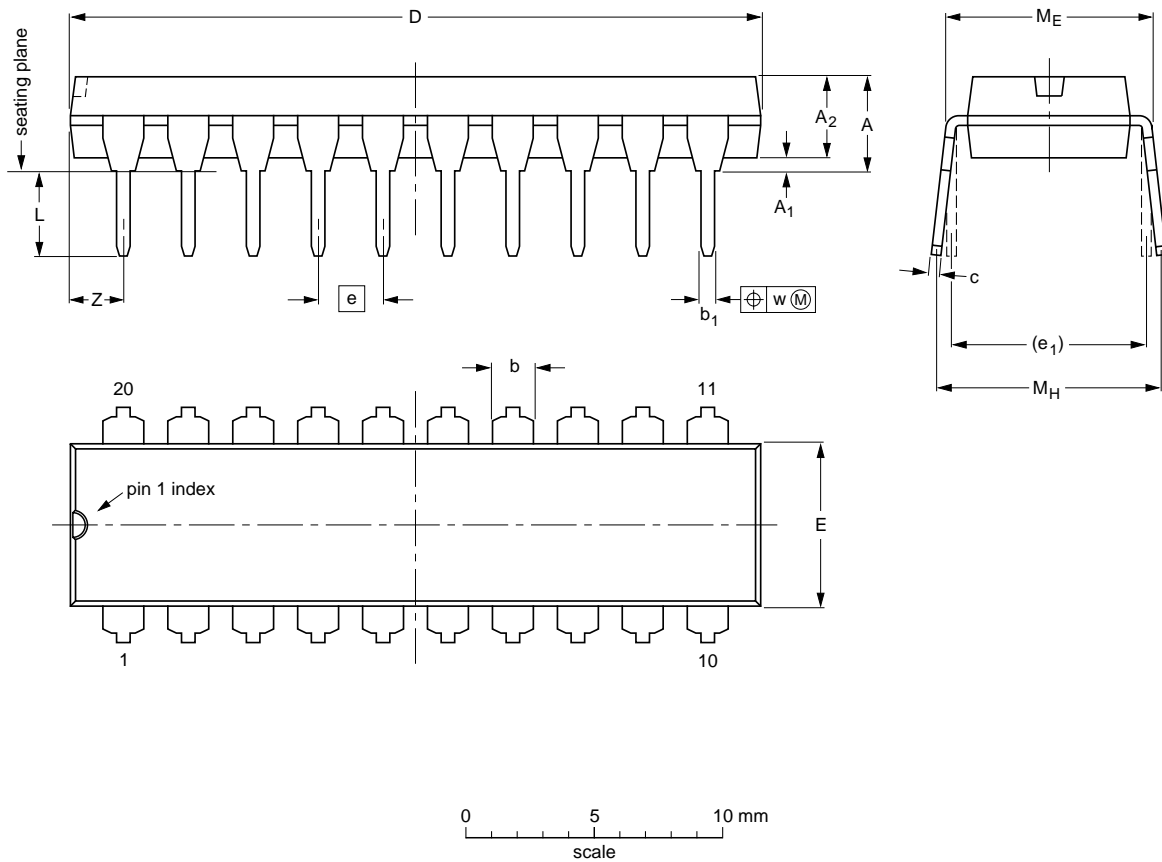
$\sum (C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.



13. Package outline

DIP20: plastic dual in-line package; 20 leads (300 mil)

SOT146-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

| UNIT   | A max. | A <sub>1</sub> min. | A <sub>2</sub> max. | b              | b <sub>1</sub> | c              | D <sup>(1)</sup> | E <sup>(1)</sup> | e    | e <sub>1</sub> | L            | M <sub>E</sub> | M <sub>H</sub> | w     | Z <sup>(1)</sup> max. |
|--------|--------|---------------------|---------------------|----------------|----------------|----------------|------------------|------------------|------|----------------|--------------|----------------|----------------|-------|-----------------------|
| mm     | 4.2    | 0.51                | 3.2                 | 1.73<br>1.30   | 0.53<br>0.38   | 0.36<br>0.23   | 26.92<br>26.54   | 6.40<br>6.22     | 2.54 | 7.62           | 3.60<br>3.05 | 8.25<br>7.80   | 10.0<br>8.3    | 0.254 | 2                     |
| inches | 0.17   | 0.02                | 0.13                | 0.068<br>0.051 | 0.021<br>0.015 | 0.014<br>0.009 | 1.060<br>1.045   | 0.25<br>0.24     | 0.1  | 0.3            | 0.14<br>0.12 | 0.32<br>0.31   | 0.39<br>0.33   | 0.01  | 0.078                 |

Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

| OUTLINE VERSION | REFERENCES |        |        |  | EUROPEAN PROJECTION |
|-----------------|------------|--------|--------|--|---------------------|
|                 | IEC        | JEDEC  | JEITA  |  |                     |
| SOT146-1        |            | MS-001 | SC-603 |  |                     |

Fig 8. Package outline SOT146-1 (DIP20)